# INTEGRATED CIRCUITS

# DATA SHEET

# **74LVC04A**Hex inverter

Product specification Supersedes data of 1997 Jun 30 2002 Mar 08





Hex inverter 74LVC04A

# **FEATURES**

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- · Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- Specified from -40 to +85 °C and -40 to +125 °C.

# **DESCRIPTION**

The 74LVC04A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC04A provides six inverting buffers.

# **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb} = 25 \, ^{\circ}C$ ;  $t_r = t_f \le 2.5 \, \text{ns}$ .

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	$C_L = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	2.1	ns
C <sub>I</sub>	input capacitance		4.0	pF
C <sub>PD</sub>	power dissipation capacitance per gate	V <sub>CC</sub> = 3.3 V; notes 1 and 2	15	pF

# **Notes**

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \Sigma (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$$

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

2. The condition is  $V_I = GND$  to  $V_{CC}$ .

# ORDERING INFORMATION

TYPE	PACKAGES								
NUMBER	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE				
74LVC04AD	−40 to +125 °C	14	SO	plastic	SOT108-1				
74LVC04ADB	−40 to +125 °C	14	SSOP	plastic	SOT337-1				
74LVC04APW	−40 to +125 °C	14	TSSOP	plastic	SOT402-1				

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# **FUNCTION TABLE**

See note 1.

INPUTS	OUTPUTS
nA	nY
L	Н
Н	L

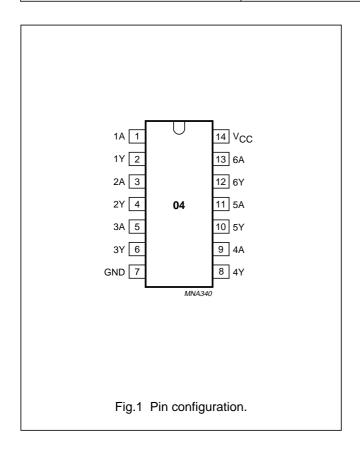
# Note

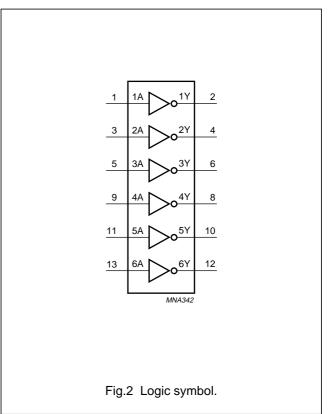
1. H = HIGH voltage level;

L = LOW voltage level.

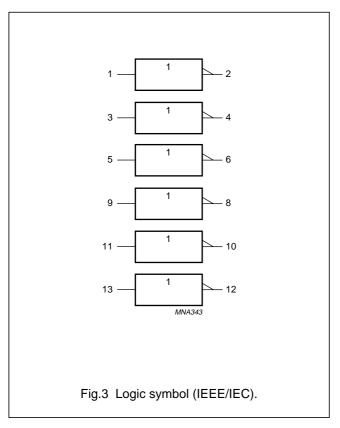
# **PINNING**

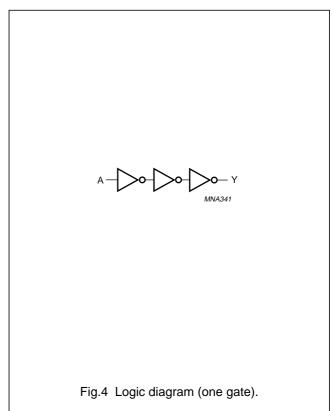
PIN	SYMBOL	DESCRIPTION
1, 3, 5, 9, 11, 13	1A to 6A	data input
2, 4, 6, 8, 10, 12	1Y to 6Y	data output
7	GND	ground (0 V)
14	V <sub>CC</sub>	supply voltage





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# **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage	for maximum speed performance	2.7	3.6	٧
		for low voltage applications	1.2	3.6	٧
VI	input voltage		0	5.5	V
Vo	output voltage		0	V <sub>CC</sub>	V
T <sub>amb</sub>	operating ambient temperature		-40	+125	°C
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	V <sub>CC</sub> = 1.2 to 2.7 V	0	20	ns/V
		V <sub>CC</sub> = 2.7 to 3.6 V	0	10	ns/V

# **LIMITING VALUES**

In accordance with the absolute maximum rating system (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input diode current	V <sub>I</sub> < 0	_	-50	mA
V <sub>I</sub>	input voltage	note 1	-0.5	+6.5	V
I <sub>OK</sub>	output diode current	$V_O > V_{CC}$ or $V_O < 0$	_	±50	mA
Vo	output voltage	note 1	-0.5	V <sub>CC</sub> + 0.5	V
Io	output source or sink current	$V_O = 0$ to $V_{CC}$	_	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	V <sub>CC</sub> or GND current		_	±100	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	power dissipation per package				
	SO package	above 70 °C derate linearly with 8 mW/K	_	500	mW
	SSOP and TSSOP packages	above 60 °C derate linearly with 5.5 mW/K	_	500	mW

# Note

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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# **DC CHARACTERISTICS**

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

		TEST CONDIT	TIONS			T <sub>amb</sub> (°C	:)			
SYMBOL	PARAMETER	OTHER	V 00	-4	0 to +85		–40 to +	-125	UNIT	
		OTHER	V <sub>CC</sub> (V)	MIN.	<b>TYP.</b> (1)	MAX.	MIN.	MAX.		
V <sub>IH</sub>	HIGH-level		1.2	V <sub>CC</sub>	_	_	V <sub>CC</sub>	_	V	
	input voltage		2.7 to 3.6	2.0	_	_	2.0	_	V	
V <sub>IL</sub>	LOW-level		1.2	_	_	GND	_	GND	V	
	input voltage		2.7 to 3.6	_	_	0.8	_	0.8	V	
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O} = -100 \mu A$	2.7 to 3.6	V <sub>CC</sub> – 0.2	_	-	V <sub>CC</sub> – 0.3	_	V	
		$I_0 = -12 \text{ mA}$	2.7	V <sub>CC</sub> – 0.5	_	-	V <sub>CC</sub> – 0.65	_	V	
		$I_{O} = -18 \text{ mA}$	3.0	V <sub>CC</sub> – 0.6	_	-	$V_{CC} - 0.75$	_	V	
		$I_{O} = -24 \text{ mA}$	3.0	V <sub>CC</sub> – 0.8	_	_	V <sub>CC</sub> – 1	_	V	
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 100 μA	2.7 to 3.6	_	_	0.2	_	0.3	V	
		I <sub>O</sub> = 12 mA	2.7	_	_	0.4	_	0.6	V	
		I <sub>O</sub> = 24 mA	3.0	_	_	0.55	_	0.8	V	
<u> </u>	input leakage current	$V_I = 5.5 \text{ V or GND}$	3.6	_	±0.1	±5	_	±20	μΑ	
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	3.6	_	0.1	10	_	40	μΑ	
Δl <sub>CC</sub>	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 0.6V;$ $I_{O} = 0$	2.7 to 3.6	_	5	500	_	5000	μΑ	

# Note

<sup>1.</sup> All typical values are measured at  $V_{CC}$  = 3.3 V and  $T_{amb}$  = 25 °C.

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# **AC CHARACTERISTICS**

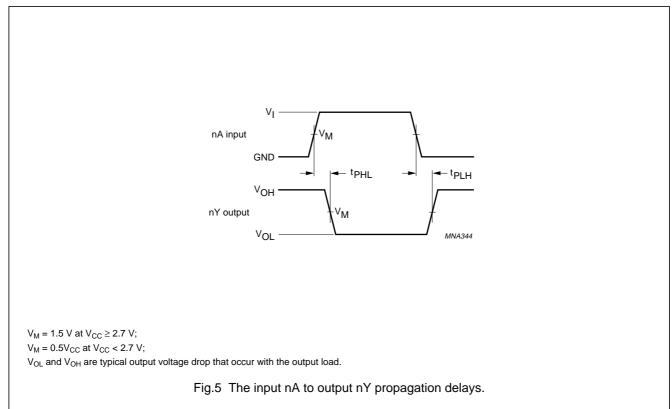
GND = 0 V;  $t_r = t_f \le 2.5 \text{ ns.}$ 

SYMBOL	PARAMETER	WAVEFORMS	-	-40 to +8	5	−40 to	UNIT				
			MIN.	<b>TYP.</b> (1)	MAX.	MIN.	MAX.				
V <sub>CC</sub> = 1.2 V											
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 5 and 6	_	14	_	_	_	ns			
$V_{CC} = 2.7 \text{ V}$											
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 5 and 6	1.5	2.2	5.5	1.5	7.0	ns			
V <sub>CC</sub> = 3.0 to 3.6 V											
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	see Figs 5 and 6	1.0	1.9	4.5	1.0	6.0	ns			
t <sub>sk(0)</sub>	skew	note 2	-	_	1.0	_	1.5	ps			

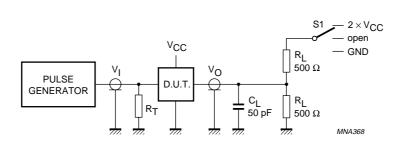
# **Notes**

- 1. All typical values are measured at  $V_{CC}$  = 3.3 V.
- 2. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

# **AC WAVEFORMS**



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V <sub>CC</sub>	VI	t <sub>PLH</sub> /t <sub>PHL</sub>
1.2 V	V <sub>CC</sub>	open
2.7 V	2.7 V	open
3.0 to 3.6 V	2.7 V	open

Definitions for test circuits:

R<sub>L</sub> = Load resistor.

 $C_L$  = Load capacitance including jig and probe capacitance (see Chapter "AC characteristics").

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

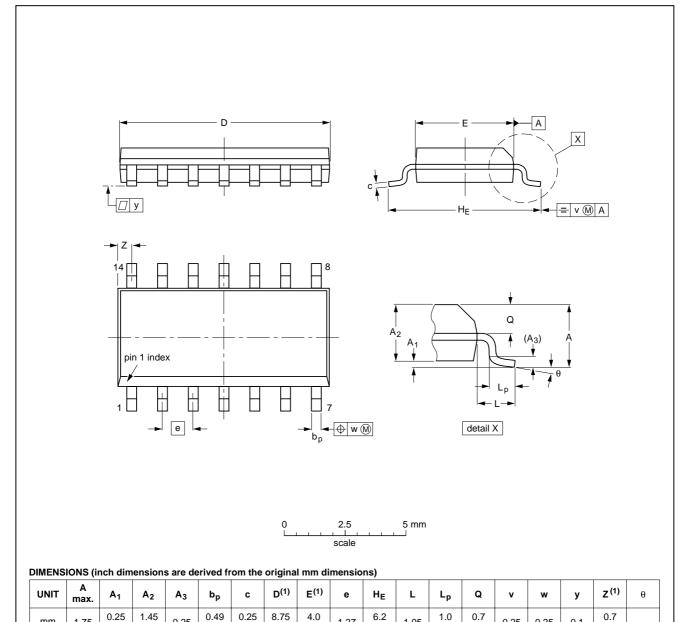
Fig.6 Load circuitry for switching times.

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# **PACKAGE OUTLINES**

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



# Note

mm

inches

1.75

0.069

0.010

0.004

0.057

0.049

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

0.25

0.01

0.19

0.35

0.34

0.019 0.0100 0.014 0.0075

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012				<del>97-05-22</del> 99-12-27

1.27

0.050

0.244

0.228

3.8

0.16

0.15

1.05

0.041

0.039

0.016

0.028

0.024

0.25

0.01

0.25

0.01

0.1

0.004

0.3

0.028

0.012

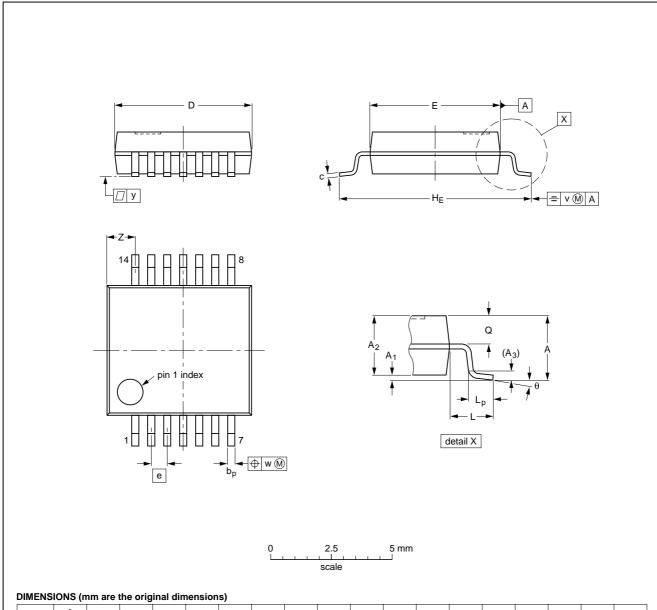
0°

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# SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

# Note

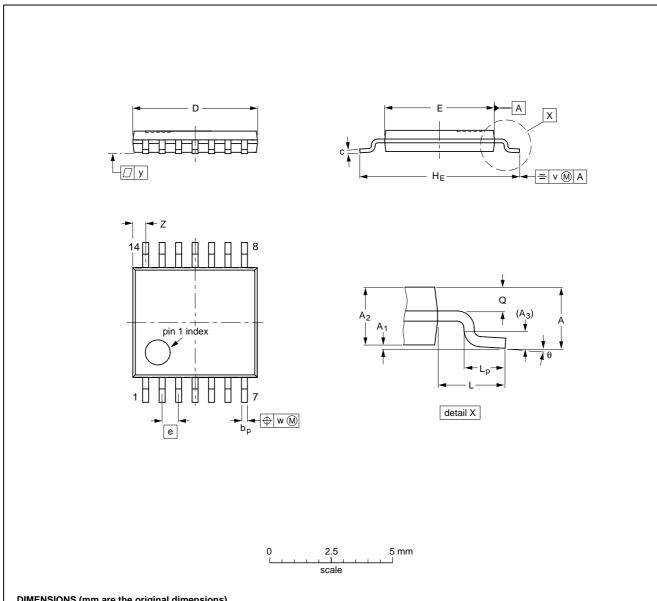
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLII	NE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	ON	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT33	37-1		MO-150			<del>-96-01-18</del> 99-12-27	

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



# **DIMENSIONS** (mm are the original dimensions)

						-,												
UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION		IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
	SOT402-1		MO-153				<del>95-04-04</del> 99-12-27	
		1					I .	_

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# SOLDERING

# Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

# Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

# Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
  - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

# Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to  $300\ ^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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# Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD				
PACKAGE	WAVE	REFLOW <sup>(1)</sup>			
BGA, HBGA, LFBGA, SQFP, TFBGA	not suitable	suitable			
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, SMS	not suitable(2)	suitable			
PLCC <sup>(3)</sup> , SO, SOJ	suitable	suitable			
LQFP, QFP, TQFP	not recommended <sup>(3)(4)</sup>	suitable			
SSOP, TSSOP, VSO	not recommended <sup>(5)</sup>	suitable			

### **Notes**

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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# **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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# **Notes**

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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